EAST Search History

| Ref# | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|------|-------|---|---|---------------------|---------|---------------------|
| S91 | 10288 | 257/25,81,91,95,98-100,103. ccls. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 17:03 |
| S90 | 2936 | 216/24,41.cds. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 17:03 |
| S89 | 4027 | 438/22,46,47,918,9.ccls. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 17:03 |
| S88 | 3 | "20020132083" | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 13:45 |
| S87 | 45 | imprint\$3 same teos | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 13:41 |
| S86 | 64 | imprint same ((silicon- containing) or teos) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 13:36 |
| S85 | 27 | (teos with pmma) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 13:32 |
| S81 | 2316 | mask with (teos or hmda) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 13:28 |

| S80 | 2316 | mask with teos | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 12:12 |
|-----|------|--|---|-----|----|---------------------|
| S79 | 93 | (micro\$1contact print\$3 or nano\$1imprint\$3 or mold or emboss\$3) and (silicon- containing) and teos | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:48 |
| S78 | 3072 | (micro\$1contact print\$3 or nano\$1imprint\$3 or mold or emboss\$3) and (silicon- containing) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:48 |
| S77 | 3974 | (micro\$1contact print\$3 or nano\$1imprint\$3 or mold or emboss\$3) and (silicon- containing or hmds) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:47 |
| S76 | 0 | (micro\$1contact print\$3 or nano\$1imprint\$3 or emboss \$3) and S75 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:46 |
| S75 | 242 | (TEOS or TMOS) with hmds | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:44 |
| S74 | 230 | TEOS with hmds | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:43 |
| S73 | 3 | (micro\$1contact print\$3 or nano\$1imprint\$3 or mold or emboss\$3) and S66 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:36 |
| S72 | 0 | S66 and S70 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:36 |

| S71 | 353 | S70 and (@ad<"20031112" OR @pd<"20031111") | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:27 |
|-----|-----|---|---|-----|----|---------------------|
| S70 | 575 | (micro\$1contact print\$3 or nano\$1imprint\$3 or mold or emboss\$3) same (TEOS or TMOS) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:27 |
| S69 | 22 | mask same mold same TEOS | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:24 |
| S68 | 1 | resist same mold same TEOS | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:24 |
| S67 | 0 | resist with mold with TEOS | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:23 |
| S66 | 402 | S65 and (@ad<"20031112" OR @pd<"20031111") | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:22 |
| S65 | 591 | S63 same etch\$4 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:21 |
| S64 | 487 | S63 and (@ad<"20031112" OR @pd<"20031111") | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:20 |
| S63 | 785 | resist with TEOS | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:20 |

| S62 | 84 | S49 and S59 and (@ad<"20031112" OR @pd<"20031111") | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:18 |
|-----|-------|--|---|-----|----|---------------------|
| S61 | 11 | S60 and (@ad<"20031112" OR @pd<"20031111") | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:16 |
| S60 | 78 | (photonic crystal) and S59 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:16 |
| S59 | 2091 | (micro\$1contact print\$3 or nano-imprint\$3 or mold) same resist same etch\$4 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:16 |
| S58 | 15188 | (micro\$1contact print\$3 or nano-imprint\$3 or mold) same resist | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:15 |
| S57 | 70 | S56 and (@ad<"20031112" OR @pd<"20031111") | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:10 |
| S56 | 192 | (photonic crystal) same resist | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:10 |
| S55 | 10 | (photonic crystal) same (mold) same resist | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 11:09 |
| S54 | 12 | S52 and resist | USPAT | ADJ | ON | 2008/12/02 10:55 |

| S53 | 0 | S52 and (@ad<"20031112" OR @pd<"20031111") | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 10:54 |
|-----|--------|--|---|-----|----|---------------------|
| S52 | 20 | ("2005/0082545").URPN. | USPAT | ADJ | ON | 2008/12/02 10:49 |
| S51 | 2 | S50 and "20050082545" | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 10:43 |
| S50 | 89 | S47 and S49 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 10:33 |
| S49 | 304219 | (light-emitting OR light emitting OR electroluminescen\$2 OR electro-luminescen\$2) ADJ (diode OR device OR apparatus OR structure) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 10:33 |
| S48 | 2106 | S47 and (master or mold) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 10:32 |
| S47 | 2231 | S46 and (@ad<"20031112" OR @pd<"20031111") | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 10:31 |
| S46 | 3466 | S44 same resist same etch\$4 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 10:30 |
| S45 | 21611 | S44 same resist | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 10:29 |

| S44 | 1545211 | master or mold or imprint | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 10:29 |
|-----|---------|--|---|-----|----|---------------------|
| S43 | 33 | US-20040253817-\$.DID. OR US-4394196-\$.DID. OR US-5981354-\$.DID. OR US-6080659-\$.DID. OR US-6136662-\$.DID. OR US-6143625-\$.DID. OR US-6288454-\$.DID. OR US-6375870-\$.DID. OR US-6610463-\$.DID. OR US-4301322-\$.DID. OR US-4381700-\$.DID. OR US-6924023-\$.DID. OR US-6949199-\$.DID. OR US-69694793-\$.DID. OR US-69694793-\$.DID. OR US-6964793-\$.DID. OR US-6964793-\$.DID. OR US-6964793-\$.DID. OR US-6964793-\$.DID. OR US-6964793-\$.DID. OR US-6964793-\$.DID. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 10:16 |
| S42 | 35 | S41 and (resist) and mold | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 10:09 |
| S41 | 225 | ((Imada near2 Aya) or (tohru near2 den)).inv. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 10:08 |
| S40 | 1 | ("2004/0253817").URPN. | USPAT | ADJ | ON | 2008/12/02 10:05 |
| S39 | 1 | "10575489" | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/12/02 09:38 |

12/3/2008 9:22:11 AM

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